NSN 5961-01-283-9040

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Inclosure Material:

Metal

Overall Length:

0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.195 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-72

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Terminal Circle Diameter:

0.110 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-15.0 collector to base voltage/static/emitter open and -15.0 collector to emitter voltage/static/base open and -4.5 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

-30.00 milliamperes source cutoff current

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector absolute

Transfer Ratio:

25.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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